IN THE CLAIMS:

Claims 1-18 have been amended herein. All of the pending claims 1 through 18 are presented below. This listing of claims will replace all prior versions and listings in the application. Please enter these claims as amended.

- 1. (Currently Amended) A method for <u>processing</u> semiconductor dice on a wafer in a process-comprising:
- determining defects on-said the semiconductor dice on-said the wafer;
- classifying each of said the defects by size and location, said determining and said classifying comprising classifying each of said the defects into one of size range populations of defects;
- assigning a weight to said-each of-said the defects representing an estimated effect of said-each-of said defects defect on die yield for-said the semiconductor dice;
- determining an estimated die yield loss (DYL) for each semiconductor die of-said the semiconductor dice based on number and weight of said the defect(s) on said each semiconductor die of said the semiconductor dice, determining said the estimated die yield loss (DYL) DYL including calculating an estimated die yield loss having lower and upper limits;
- summing all-said of the DYL of-said the semiconductor dice on-said the wafer to obtain a wafer yield loss (WYL);
- subdividing the defects into a plurality of size range populations of defects for said the semiconductor dice; and
- determining a relative contribution of each size range population of defects of-said the plurality of said the semiconductor dice to-said the wafer yield loss WYL.
- 2. (Currently Amended) The method of claim 1, wherein said-determining-said the estimated die yield loss (DYL) DYL comprises calculating an estimated die yield loss having lower and upper limits of zero and 1.0, respectively.

- 3. (Currently Amended) The method of claim 2, wherein said the lower limit comprises a representation of no yield loss attributable to said the defects and said the upper limit comprises a representation of fatal yield loss attributable to said the defects.
- 4. (Currently Amended) The processing method of claim 1, wherein said subdividing said the defects into said the plurality of size range populations of defects comprises subdividing said the defects into a plurality of 0 to 10 size range populations.
- 5. (Currently Amended) A method for semiconductor dice on a wafer comprising: determining defects on-said the semiconductor dice on-said the wafer;
- classifying each of said the defects by size and location, said inspecting determining and said classifying comprising classifying each of said the defects into one of size range populations of defects;
- assigning a weight to said each of said the defects representing an estimated effect of said the defects on die yield for said the semiconductor dice;
- determining an estimated die yield loss (DYL) for each semiconductor die of-said the semiconductor dice based on number and weight of-said the defect(s) defects on said each semiconductor die of-said the semiconductor dice;
- summing all DYL of-said the semiconductor dice on-said the wafer to obtain a wafer yield loss (WYL);
- subdividing the defects into a plurality of size range populations of defects; and determining a relative contribution of each size range population of defects of-said the plurality to-said wafer yield loss the WYL, said wherein determining the relative contribution of said each size range population of defects of-said the plurality to-said the wafer yield loss comprises:
 - discarding data for said each size range population of defects of said the plurality and calculating, in turn, a drop in said wafer yield loss the WYL for combined size range populations excepting the discarded data;

summing the calculated wafer yield losses WYL to obtain a drop sum; dividing said the drop sum to determine a relative drop attributable to said each size range population of defects of said the plurality; and randomly selecting defects from said each size range population of defects of the plurality.

- 6. (Currently Amended) The processing method of claim-2_5, further comprising: randomly selecting defects from said each size range population of defects of said the plurality, a number selected from said each size range population of defects of said the plurality in proportion to said the relative contribution thereof, said the randomly selected defects being weighted to represent defects having having a greatest effect on yield losses.
- 7. (Currently Amended) The processing method of claim 6, further comprising: reviewing-said the randomly selected defects and determining in-line action required to reduce wafer yield losses.
- 8. (Currently Amended) The processing method of claim 7, wherein said-reviewing said the randomly selected defects includes visual inspection by a microscope.
- 9. (Currently Amended) The processing-method of claim 7, wherein said determining in-line action comprises determining if an individual semiconductor die of said the semiconductor dice on said the wafer is acceptable to proceed in a manufacturing process.
- 10. (Currently Amended) The processing-method of claim 5, wherein-said inspecting determining defects on the said semiconductor dice is performed by an automated surface inspection tool.

11. (Currently Amended) A method for semiconductor dice in wafer form comprising:

determining defects of-said the semiconductor dice;

classifying each of said the defects by size and location;

- assigning a weight to said-each of said the defects representing an estimated effect of said-each of said defects defect on die yield;
- determining an estimated die yield loss (DYL) for each of the semiconductor dice die-based on number and weight of-said defect(s) the defects on said each-said die of said the semiconductor dice;
- summing all DYL of-said the semiconductor dice on-said the wafer to obtain a wafer yield loss (WYL);

subdividing the defects into a plurality of size range populations of defects;

- determining a relative contribution of each size range population of defects of said the plurality to said wafer yield loss the WYL;
- randomly selecting defects from said-each size range population of defects of the plurality, a number selected from said-each size range population of defects of the plurality in proportion to said the relative contribution thereof, said the randomly selected defects weighted to represent defects having having a greatest effect on yield losses; and reviewing said the randomly selected defects.
- 12. (Currently Amended) The method of claim 11, further comprising: reviewing-said the randomly selected defects and determining in-line action required to reduce said the wafer yield losses WYL.
- 13. (Currently Amended) The processing-method of claim 11, wherein-said inspecting on said wafer said dice determining defects and said-classifying each of said the defects comprises classifying each of said the defects into one of said the plurality of size range populations of defects.

- 14. (Currently Amended) The processing method of claim 11, wherein said determining said estimated die yield loss (DYL) the DYL comprises calculating an estimated die yield loss having lower and upper limits of zero and 1.0, respectively.
- 15. (Currently Amended) The processing method of claim 14, wherein-said the lower limit comprises a representation of no yield loss attributable to-said the defects and said the upper limit comprises a representation of fatal yield loss attributable to-said the defects.
- 16. (Currently Amended) The processing method of claim 11, wherein said subdividing said the defects into said the plurality of size range populations of defects comprises subdividing said the defects into a plurality of 0 to 10 size range populations.
- 17. (Currently Amended) The processing-method of claim 11, wherein said determining the relative contribution of said-each size range population of defects of-said the plurality to-said wafer yield loss the WYL comprises:

discarding data for said-each size range population of defects of-said the plurality and calculating, in turn, a drop in-said wafer yield loss WYL for combined size range populations excepting the discarded data;

summing the calculated drop in-wafer yield losses WYL to obtain a drop sum; and dividing-said the drop sum to determine a relative drop attributable to said each size range population of defects of-said the plurality.

18. (Currently Amended) The method of claim 12, wherein said-determining in-line action required to reduce-said wafer yield losses the WYL comprises determining if an individual semiconductor die of-said the semiconductor dice-on-said in wafer form is acceptable to proceed in a manufacturing process.